"Yـ / Descriptions

SOT-323 NPN Silicon NPN transistor in a SOT-323 Plastic Package.

◕ È / Features

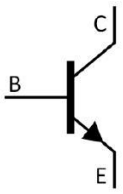
BC858W

High current, low voltage complementary pair with BC858W.

¥ ¸ / Applications

General purpose switching and amplification.

Л ف̃ ǫ̃ ≠ ع / Equivalent Circuit



ã ﻉ ṻ / Pinning



PIN1 Emitter PIN 2 Base PIN 3 Collector

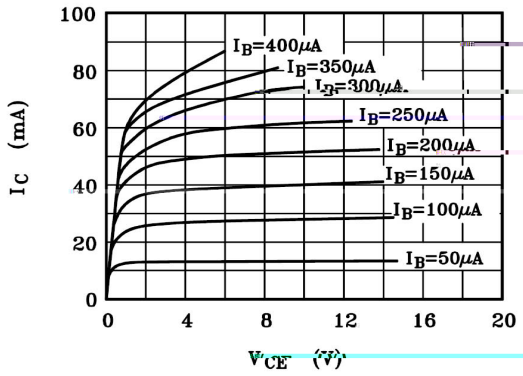
ł. ʜ ڸ / Marking

h_{FE} Classifications Symbol	A	B	C
h_{FE} Range	110 220	200 450	420 800
Marking	H1J	H1K	H1L

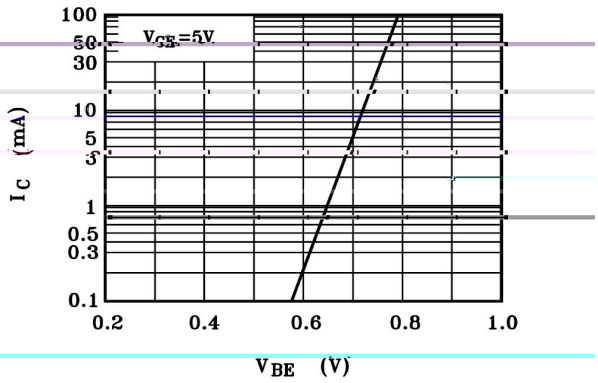
Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	30	V
Collector to Emitter Voltage	V_{CEO}	30	V
Emitter to Base Voltage	V_{EBO}	5.0	V
Collector Current- Continuous	I_C	100	mA
Peak Collector Current - Continuous	I_{CM}	200	mA
Collector Power Dissipation	P_C	200	mW

≠ ∃ Ã´E ∀ ƒ / Electrical Characteristic Curve

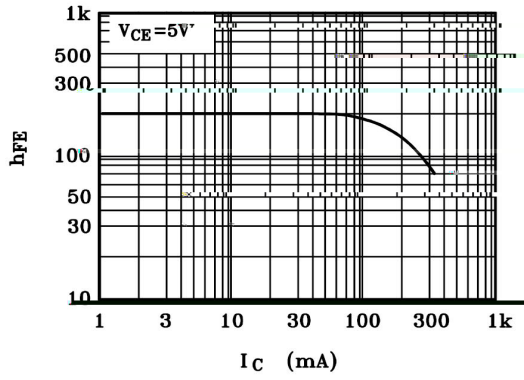
$I_C - V_{CE}$



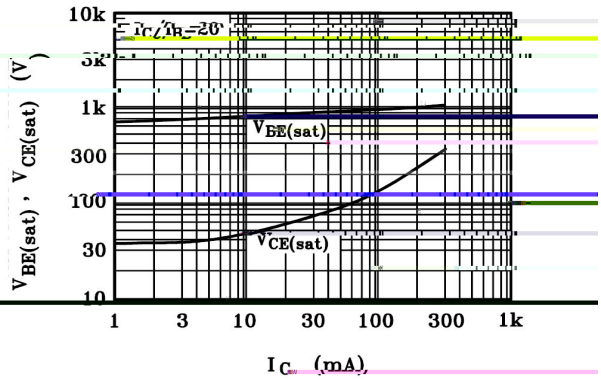
$I_C - V_{BE}$



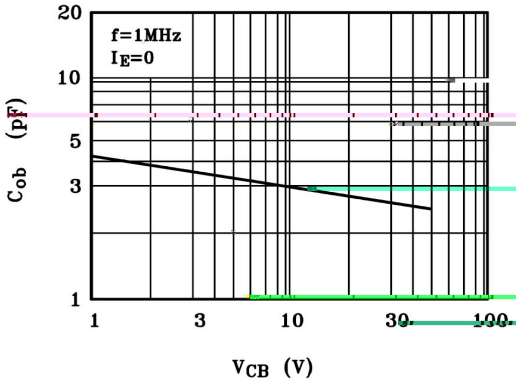
$h_{FE} - I_C$



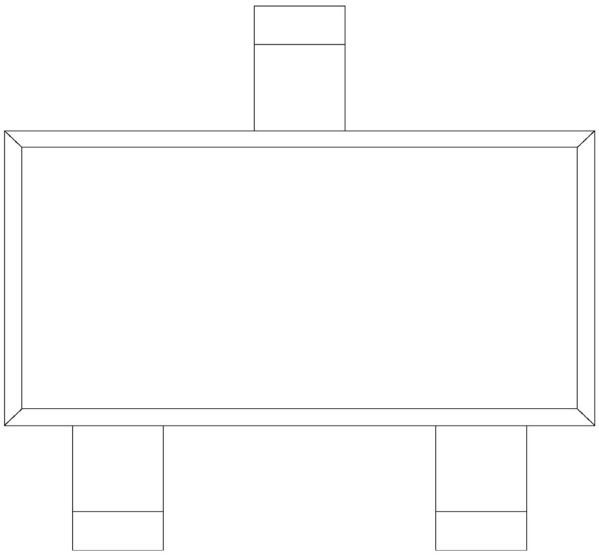
$V_{BE(sat)}$, $V_{CE(sat)} - I_C$



$C_{ob} - V_{CB}$



Ł. Ł Ω / Marking Instructions



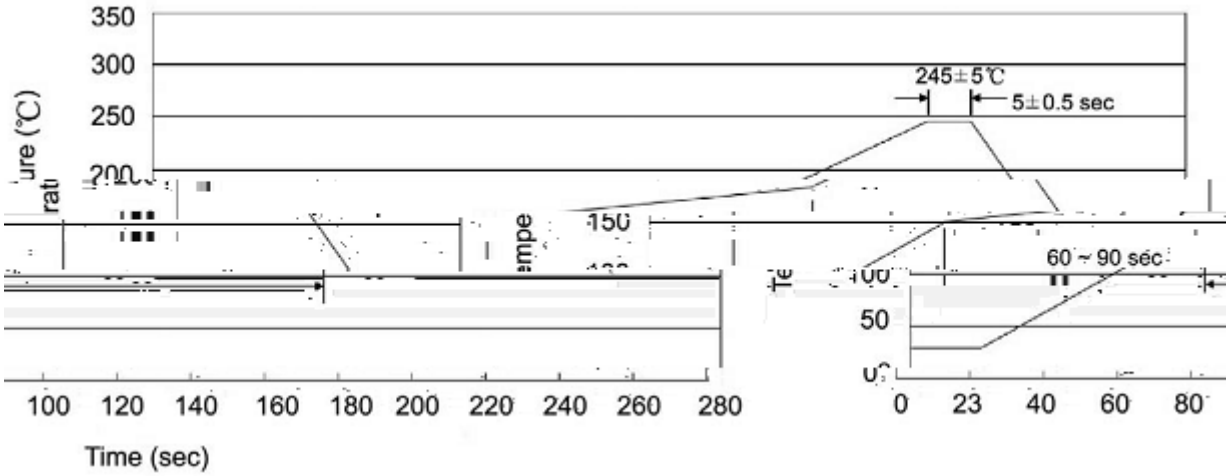
H

1J

Note:

H: Note(5)Tuctions Tf5284

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Note:

1	25	150	60	90sec;	1.Preheating:25~150 , Time:60~90sec.
2	245±5			5±0.5sec;	2.Peak Temp.:245±5 , Duration:5±0.5sec.
3		2	10	/sec.	3. Cooling Speed: 2~10 /sec.

ⅎ ü q ‗ `Y Ţ / Resistance to Soldering Heat Test Conditions

260±5	10±1 sec.	Temp.:260±5	Time:10±1 sec

ɔ Ł ≤ — / Packaging SPEC.

/ REEL

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm^3)		
	Units/Reel 只/卷盘	Reels/Inner Box 卷盘/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Reel	Inner Box 盒	Outer Box 箱
SOT-323	3,000	10	30,000	6	180,000	7 ×8	180×120×180	390×385×205